Datasheet

SiC Schottky Barrier Diode

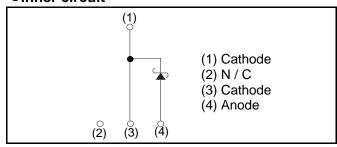
V_R	650V
I _F	20A
Q_{C}	31nC

● Outline LPT(L) <TO-263AB> (2) (3) (4)

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

•Inner circuit



Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

Packaging specifications

	ging opositioations	
	Packaging	Embossed tape
	Reel size (mm)	330
Tuno	Tape width (mm)	24
Туре	Basic ordering unit (pcs)	1 000
	Packing code	TLL
	Marking	SCS220AJ

•Absolute maximum ratings $(T_i = 25^{\circ}C)$

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		V_{RM}	650	V
Reverse voltage (D	C)	V_R	650	V
Continuous forward	current (T _c = 116°C)	I _F	20	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		68	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I _{FSM}	53	А
current	PW=10μs square, T _j =25°C		260	А
Repetitive peak forward current		I _{FRM}	71 * ¹	А
PW=10ms, T _j =25°C		۲.2 _ا ،	23	A ² s
i ² t value	PW=10ms, T _j =150°C	$\int i^2 dt$	14	A ² s
Total power dissipation		P_{D}	100*2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_j=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter	Symbol	Conditions	Values			Linit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =4.0mA	650	-	-	V
	V _F	I _F =20A,T _j =25°C	-	1.35	1.55	V
Forward voltage		I _F =20A,T _j =150°C	-	1.55	-	V
		I _F =20A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,T _j =25°C	-	4	400	μΑ
		V _R =600V,T _j =150°C	-	60	-	μΑ
		V _R =600V,T _j =175°C	-	140	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	730	-	pF
		V _R =600V,f=1MHz	-	74	-	pF
Total capacitive charge	Q_{C}	V _R =400V,di/dt=350A/μs	-	31	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	19	-	ns

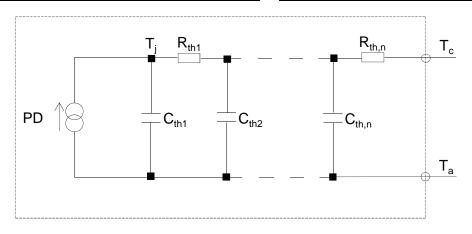
Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	-	1.1	1.4	°C/W

● Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	2.43E-02	
R _{th2}	7.53E-01	K/W
R _{th3}	3.23E-01	

Symbol	Value	Unit
C_{th1}	3.11E-03	
C_{th2}	1.03E-03	Ws/K
C_{th3}	1.55E-01	



Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

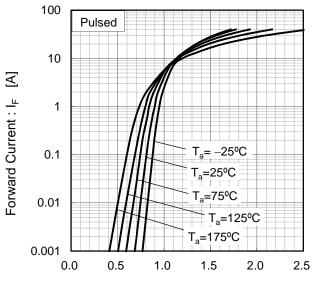
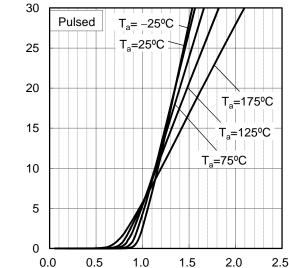


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V] Forward Voltage : V_F [V]

Forward Current : I_F [A]

Fig.3 V_R - I_R Characteristics

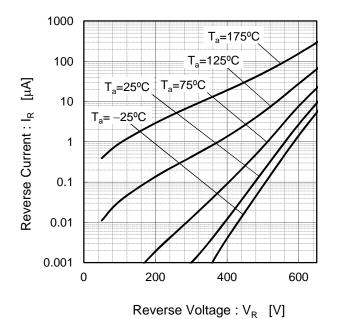
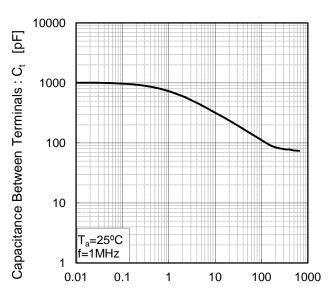
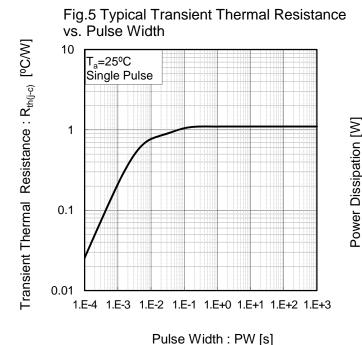


Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves



120 100 80 60 40 20 25 50 75 100 125 150 175

Case Temperature : T_c [°C]

Fig.6 Power Dissipation

Fig.7*3 Maximum peak forward current derating curve I_P - T_c 180 160 Peak Forward Current : Ip [A] 140 120 Duty=0.1 100 Duty=0.2 80 60 Duty=0.5 40 20 Duty=0.8 D.C 0 50 100 25 75 125 150 175

Case Temperature : T_c [°C]
*3 Based on max Vf, max R_{th(j-c)}
Valid for switching of above 10kHz, excluding D.C. curve.

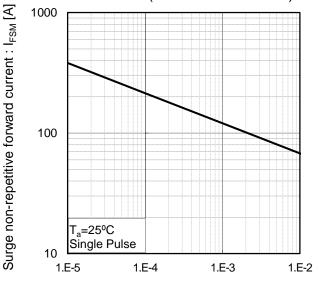
Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed) 180 160 Duty=0.1 140 120 Duty=0.2 100 80 Duty=0.5 60 40 20 Duty=0.8 D.C. 0 100 25 50 75 125 150 175

Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Peak Forward Current : Ip [A]

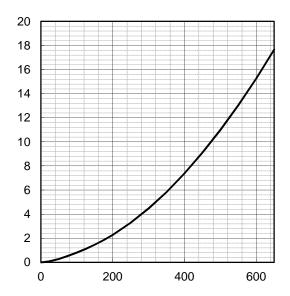
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig.10 Typical capacitance store energy

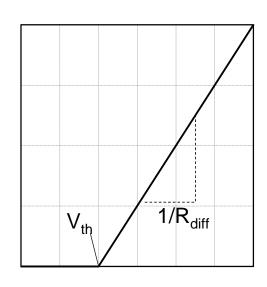


Capacitance stored energy : $\mathsf{E}_{\mathrm{C}}[\mu J]$

Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a ₀	9.35E-01	V
a ₁	-1.12E-03	V/°C
b ₀	1.99E-02	Ω
b ₁	5.10E-05	Ω/°C
b ₂	5.40E-07	Ω /°C ²

 T_{j} in °C; -55 °C < T_{j} < °C ; I_{F} < 40 A

Forward Current: IF

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